

Silicon Carbide Power MOSFET E-Series Automotive N-Channel Enhancement Mode

Features

- 3rd generation SiC MOSFET technology
- Optimized package with separate driver source pin
- 8mm of creepage distance between drain and source
- High blocking voltage with low on-resistance
- High-speed switching with low capacitances
- Fast intrinsic diode with low reverse recovery (Q_{rr})
- Halogen free, RoHS compliant
- Automotive Qualified (AEC-Q101) and PPAP Capable

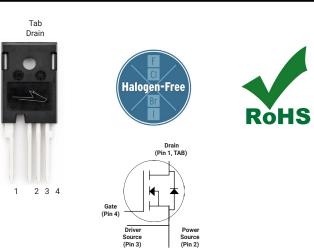
Benefits

- Reduce switching losses and minimize gate ringing
- Higher system efficiency
- Reduce cooling requirements
- Increase power density
- Increase system switching frequency

Applications

- EV Battery Chargers
- High Voltage DC/DC Converters





Part Number	Package	Marking		
E3M0060065K	TO-247-4L	E3M0060065K		

Maximum Ratings (T_c = 25 °C unless otherwise specified)

Symbol	Parameter	Value	Unit	Note	
V_{DSmax}	Drain - Source Voltage		650	V	
V_{GSmax}	Gate - Source Voltage		-8/+19	V	Note: 1
		T _C = 25°C	37	A	Fig. 19 Note: 2
I _D	Continuous Drain Current, V _{GS} = 15 V	T _C = 100°C	26		
$I_{D(pulse)}$	Pulsed Drain Current, Pulse width t_P limited by T_{jmax}	99	А	Fig. 22	
P _D	Power Dissipation, $T_c = 25^{\circ}C$, $T_J = 175^{\circ}C$	131	W	Fig. 20 Note: 2	
T_{J} , T_{stg}	Operating Junction and Storage Temperature			°C	
Τ _L	Solder Temperature, 1.6mm (0.063") from case for 10s			°C	
M_{d}	Mounting Torque , M3 or 6-32 screw		1 8.8	Nm lbf-in	

Note (1): Recommended turn off / turn on gate voltage V_{gs} - 4V...0V / +15V

Note (2): Verified by design

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions	Note
V _{(BR)DSS}	Drain-Source Breakdown Voltage	650		1	V	V _{GS} = 0 V, I _D = 100 μA	
M		1.8	2.8	3.6	V	V _{DS} = V _{GS} , I _D = 3.6 mA	Fig. 11
$V_{\text{GS(th)}}$	Gate Threshold Voltage		2.2		V	V_{DS} = V_{GS} , I_D = 3.6 mA, T_J = 175°C	
I _{DSS}	Zero Gate Voltage Drain Current		1	50	μA	V _{DS} = 650 V, V _{GS} = 0 V	
I _{GSS}	Gate-Source Leakage Current		10	250	nA	V _{GS} = 15 V, V _{DS} = 0 V	
R _{DS(on)}	Drain-Source On-State Resistance		60	79	mΩ	V _{GS} = 15 V, I _D = 13.2 A	Fig. 4,
· ·DS(on)			83			V _{GS} = 15 V, I _D = 13.2 A, T _J = 175°C	5, 6
g fs	Transconductance		9	<u> </u>	s	V _{DS} = 20 V, I _{DS} = 13.2 A	Fig. 7
			9			V _{DS} = 20 V, I _{DS} = 13.2 A, T _J = 175°C	, °
C _{iss}	Input Capacitance		1170				Fig. 17, 18
C_{oss}	Output Capacitance		72		pF	V_{GS} = 0 V, V_{DS} = 0V to 600 V	
C _{rss}	Reverse Transfer Capacitance		6			F = 1 Mhz	
E _{oss}	Coss Stored Energy		14		μJ	V _{AC} = 25 mV	Fig. 16
$C_{o(er)}$	Effective Output Capacitance (Energy Related)		85		pF		Note: 3
C _{o(tr)}	Effective Output Capacitance (Time Related)		122		pF	V _{GS} = 0 V, V _{DS} = 0 400V	
E _{ON}	Turn-On Switching Energy (External Diode)		29			$V_{DS} = 400 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}, I_{D} = 13.2\text{ A},$	Fig. 25
EOFF	Turn Off Switching Energy (External Diode)		12		μJ	$R_{G(ext)} = 2.5 \Omega$, L= 135 μH, T _J = 175°C FWD = External SiC DIODE	
E _{on}	Turn-On Switching Energy (Body Diode FWD)		40			$V_{DS} = 400 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}, I_{D} = 13.2\text{ A},$	Fig. 25
EOFF	Turn-Off Switching Energy (Body Diode FWD)		11		μJ	$R_{G(ext)} = 2.5 \Omega$, L= 135 µH, T _J = 175°C FWD = Internal Body Diode	
t _{d(on)}	Turn-On Delay Time		9				Fig. 26
tr	Rise Time		10		1	V_{DD} = 400 V, V_{GS} = -4 V/15 V I _D = 13.2 A, $R_{G(ext)}$ = 2.5 Ω,	
$t_{\text{d(off)}}$	Turn-Off Delay Time		16		ns	Timing relative to V _{DS} Inductive load	
t _f	Fall Time		8				
$R_{G(int)}$	Internal Gate Resistance		4		Ω	f = 1 MHz, V _{AC} = 25 mV	
Q_{gs}	Gate to Source Charge		16			V _{DS} = 400 V, V _{GS} = -4 V/15 V	
Q_{gd}	Gate to Drain Charge		16	1	nC	I _D = 13.2 A	Fig. 12
Qg	Total Gate Charge		49			Per IEC60747-8-4 pg 21	

Electrical Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Note (3): $C_{o(er)}$, a lumped capacitance that gives same stored energy as Coss while Vds is rising from 0 to 400V $C_{o(tr)}$, a lumped capacitance that gives same charging time as Coss while Vds is rising from 0 to 400V

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Reverse Diode Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
N	Diode Forward Voltage	4.6		V	$V_{_{GS}}$ = -4 V, I $_{_{SD}}$ = 6.6 A, T $_{_{J}}$ = 25 °C	Fig. 8, 9, 10
V _{SD}		4.1		V	V _{GS} = -4 V, I _{SD} = 6.6 A, T _J = 175 °C	
Is	Continuous Diode Forward Current		23	А	V_{gs} = -4 V, T_c = 25°C	
I _{S, pulse}	Diode pulse Current		99	А	$V_{_{GS}}$ = -4 V, pulse width $t_{\rm P}$ limited by T_{jmax}	
t _{rr}	Reverse Recover time	12		ns		
Q _{rr}	Reverse Recovery Charge	173		nC	$V_{GS} = -4 V, I_{SD} = 13.2 A, V_{R} = 400 V$ dif/dt = 4770 A/µs, T _J = 175 °C	
I _{rrm}	Peak Reverse Recovery Current	28		A		
t _{rr}	Reverse Recover time	15		ns		
Q _{rr}	Reverse Recovery Charge	122		nC	V _{GS} = -4 V, I _{SD} = 13.2 A, V _R = 400 V dif/dt = 2200 A/μs, Τ _J = 175 °C	
I _{rrm}	Peak Reverse Recovery Current	13		А		

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
R _{θJC}	Thermal Resistance from Junction to Case	1.02	1.14	°C/W		Fig. 21



Typical Performance

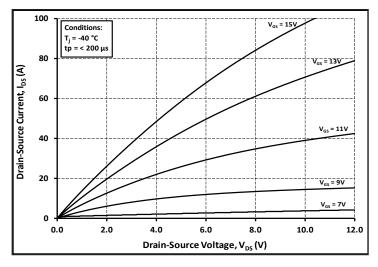
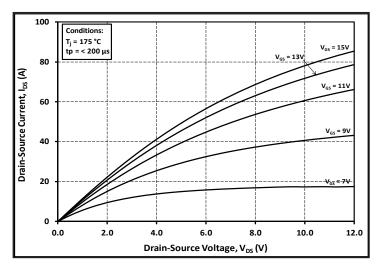


Figure 1. Output Characteristics T_J = -40 °C





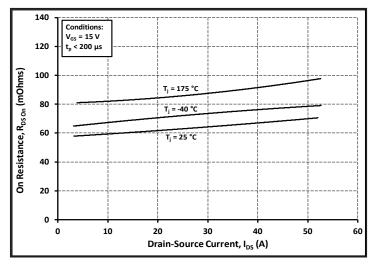
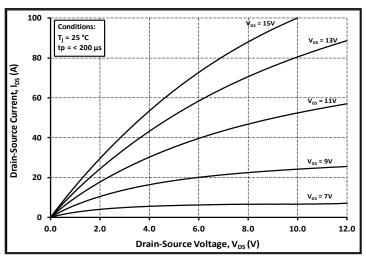
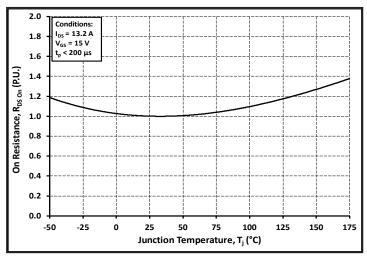


Figure 5. On-Resistance vs. Drain Current For Various Temperatures









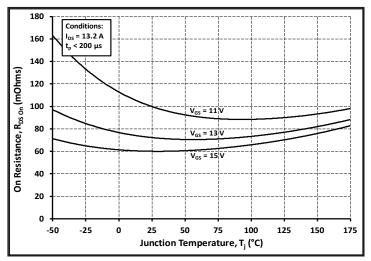


Figure 6. On-Resistance vs. Temperature For Various Gate Voltage

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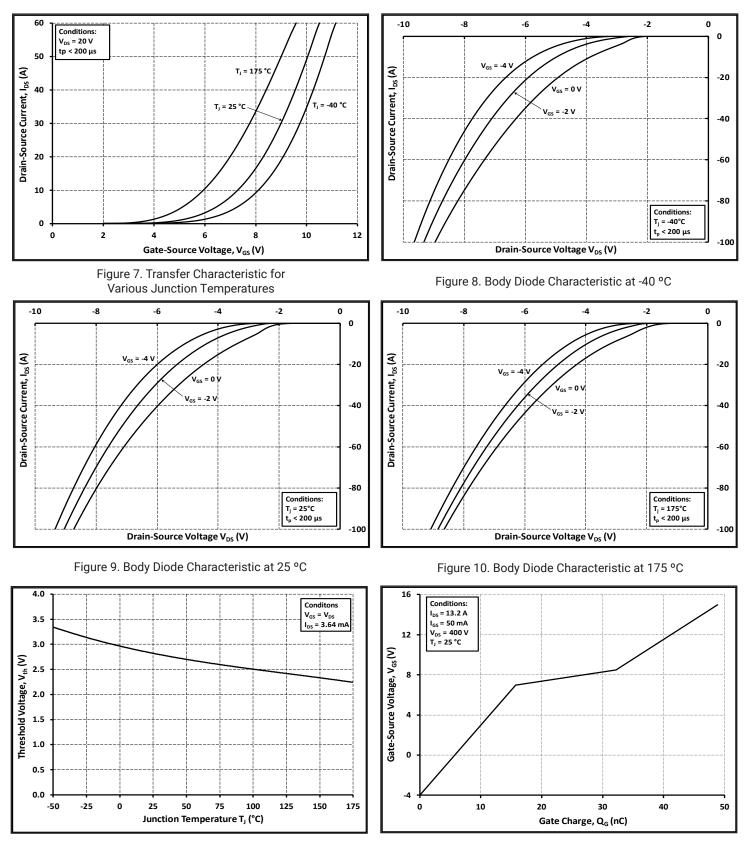


Figure 11. Threshold Voltage vs. Temperature

Figure 12. Gate Charge Characteristics

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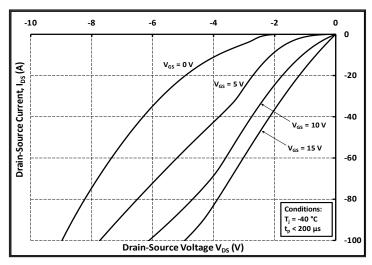


Figure 13. 3rd Quadrant Characteristic at -40 °C

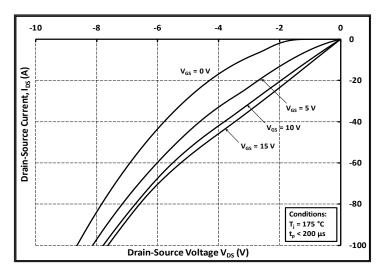
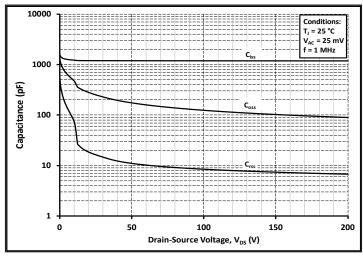
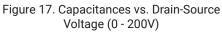


Figure 15. 3rd Quadrant Characteristic at 175 °C





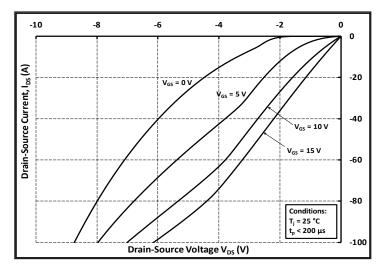


Figure 14. 3rd Quadrant Characteristic at 25 °C

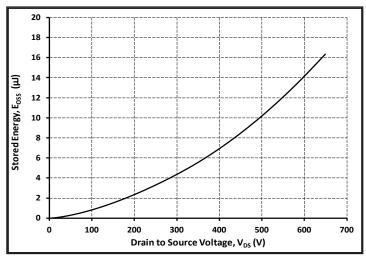


Figure 16. Output Capacitor Stored Energy

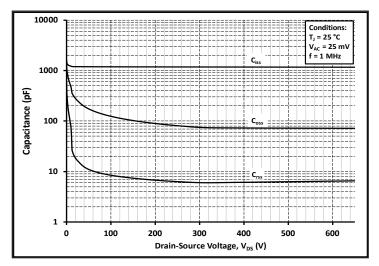


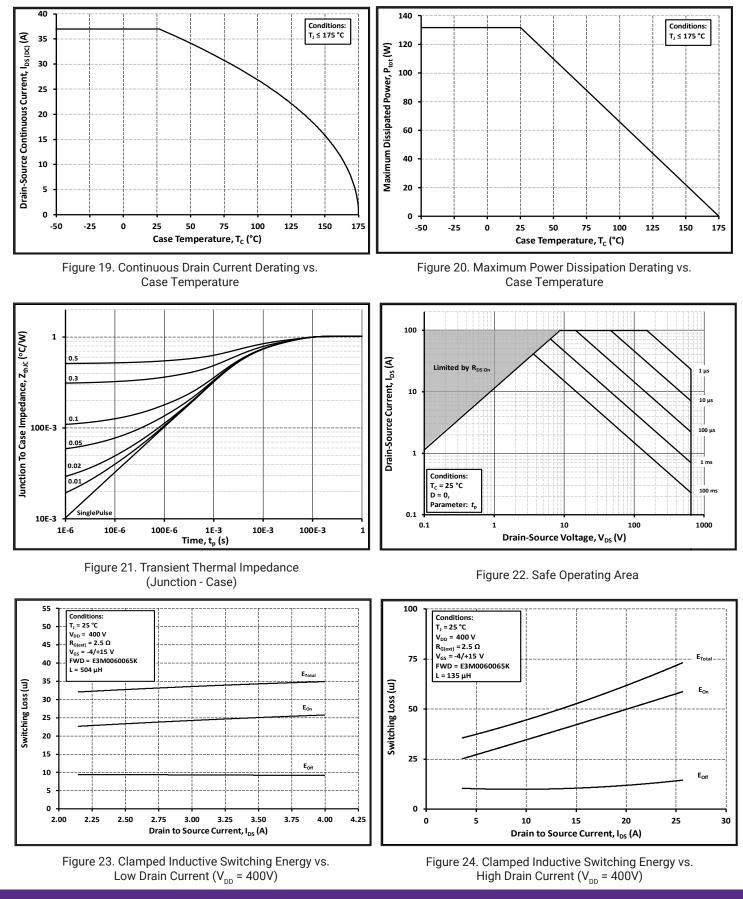
Figure 18. Capacitances vs. Drain-Source Voltage (0 - 650V)

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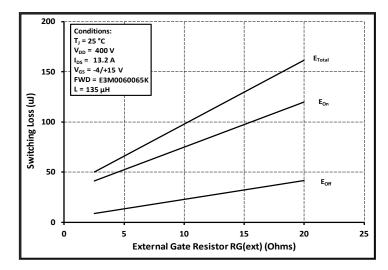


Figure 25. Clamped Inductive Switching Energy vs. $R_{G(ext)}$

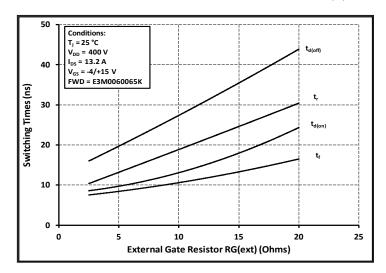


Figure 27. Switching Times vs. $R_{G(ext)}$

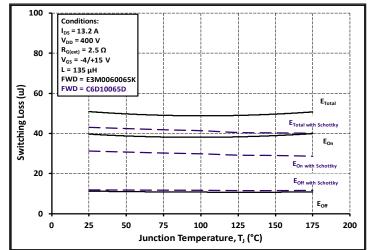


Figure 26. Clamped Inductive Switching Energy vs. Temperature

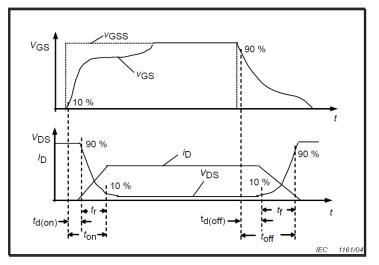


Figure 28. Switching Times Definition

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Test Circuit Schematic



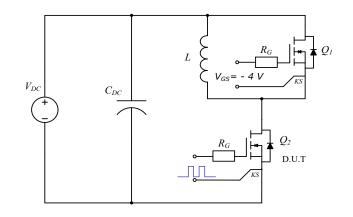


Figure 29. Clamped Inductive Switching Waveform Test Circuit

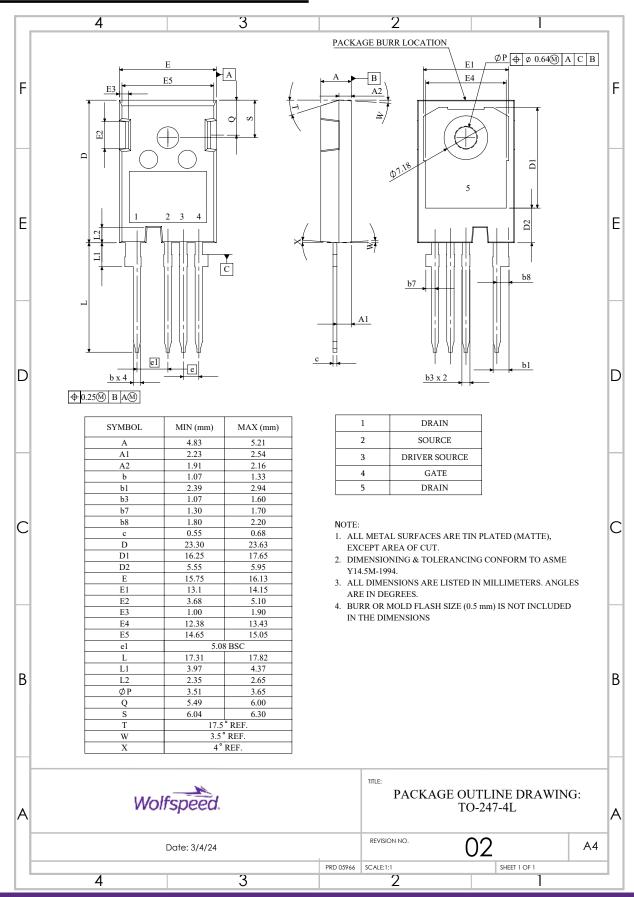
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Package Dimensions

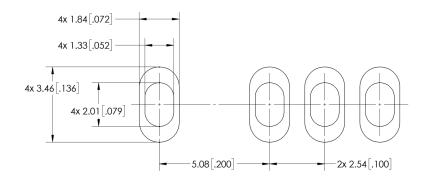


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Recommended Solder Pad Layout



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Document Version	Date of release	Descriptiion of changes
1.0	June-2022	Initial datasheet
2	January - 2025	Legal Disclaimer Updated

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